

2SJ304

DC-DC Converter, Relay Drive and Motor Drive Applications

- 4 V gate drive
- Low drain-source ON resistance : $R_{DS(ON)} = 80 \text{ m}\Omega$ (typ.)
- High forward transfer admittance : $|Y_{fs}| = 8.0 \text{ S}$ (typ.)
- Low leakage current : $I_{DSS} = -100 \text{ }\mu\text{A}$ (max) ($V_{DS} = -60 \text{ V}$)
- Enhancement-mode : $V_{th} = -0.8 \sim -2.0 \text{ V}$ ($V_{DS} = -10 \text{ V}$, $I_D = -1 \text{ mA}$)

Maximum Ratings (Ta = 25°C)

| Characteristics | Symbol | Rating | Unit |
|------------------------------------------------------|---------------|----------|------|
| Drain-source voltage | V_{DSS} | -60 | V |
| Drain-gate voltage ($R_{GS} = 20 \text{ k}\Omega$) | V_{DGR} | -60 | V |
| Gate-source voltage | V_{GSS} | ± 20 | V |
| Drain current | DC (Note 1) | I_D | -14 |
| | Pulse(Note 1) | I_{DP} | -56 |
| Drain power dissipation ($T_c = 25^\circ\text{C}$) | P_D | 40 | W |
| Channel temperature | T_{ch} | 150 | °C |
| Storage temperature range | T_{stg} | -55~150 | °C |

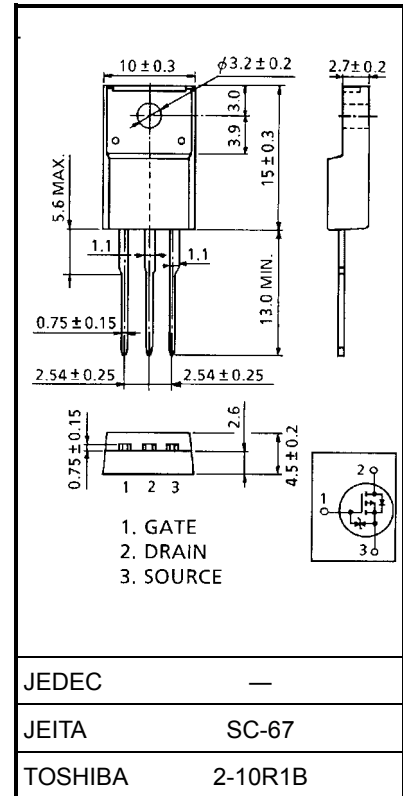
Thermal Characteristics

| Characteristics | Symbol | Max | Unit |
|----------------------------------------|----------------|-------|--------|
| Thermal resistance, channel to case | $R_{th(ch-c)}$ | 3.125 | °C / W |
| Thermal resistance, channel to ambient | $R_{th(ch-a)}$ | 62.5 | °C / W |

Note 1: Please use devices on condition that the channel temperature is below 150°C.

This transistor is an electrostatic sensitive device.
Please handle with caution.

Unit: mm



Weight: 1.9 g (typ.)

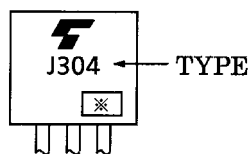
Electrical Characteristics (Ta = 25°C)

| Characteristics | | Symbol | Test Condition | Min | Typ. | Max | Unit |
|-------------------------------------------------|---------------|---------------|--------------------------------------------------------------------------|-------------------------------------------|------|----------|---------------|
| Gate leakage current | | I_{GSS} | $V_{GS} = \pm 16\text{ V}, V_{DS} = 0\text{ V}$ | — | — | ± 10 | μA |
| Drain cut-off current | | I_{DSS} | $V_{DS} = -60\text{ V}, V_{GS} = 0\text{ V}$ | — | — | -100 | μA |
| Drain-source breakdown voltage | | $V_{(BR)DSS}$ | $I_D = -10\text{ mA}, V_{GS} = 0\text{ V}$ | -60 | — | — | V |
| Gate threshold voltage | | V_{th} | $V_{DS} = -10\text{ V}, I_D = -1\text{ mA}$ | -0.8 | — | -2.0 | V |
| Drain-source ON resistance | | $R_{DS(ON)}$ | $V_{GS} = -4\text{ V}, I_D = -5\text{ A}$ | — | 130 | 190 | m Ω |
| | | | $V_{GS} = -10\text{ V}, I_D = -7\text{ A}$ | — | 80 | 120 | |
| Forward transfer admittance | | $ Y_{fs} $ | $V_{DS} = -10\text{ V}, I_D = -7\text{ A}$ | 5.0 | 8.0 | — | S |
| Input capacitance | | C_{iss} | $V_{DS} = -10\text{ V}, V_{GS} = 0\text{ V}, f = 1\text{ MHz}$ | — | 1200 | — | pF |
| Reverse transfer capacitance | | C_{rss} | | — | 220 | — | |
| Output capacitance | | C_{oss} | | — | 550 | — | |
| Switching time | Rise time | t_r | | — | 20 | — | ns |
| | Turn-on time | t_{on} | | — | 30 | — | |
| | Fall time | t_f | | — | 25 | — | |
| | Turn-off time | t_{off} | | Duty $\leq 1\%$, $t_w = 10\ \mu\text{s}$ | — | 100 | |
| Total gate charge (Gate-source plus gate-drain) | | Q_g | $V_{DD} \approx -48\text{ V}, V_{GS} = -10\text{ V}, I_D = -14\text{ A}$ | — | 45 | — | nC |
| Gate-source charge | | Q_{gs} | | — | 30 | — | |
| Gate-drain ("miller") charge | | Q_{gd} | | — | 15 | — | |

Source-Drain Ratings and Characteristics (Ta = 25°C)

| Characteristics | Symbol | Test Condition | Min | Typ. | Max | Unit |
|-------------------------------------------|-----------|----------------------------------------------|-----|------|-----|---------------|
| Continuous drain reverse current (Note 1) | I_{DR} | — | — | — | -14 | A |
| Pulse drain reverse current (Note 1) | I_{DRP} | — | — | — | -56 | A |
| Forward voltage (diode) | V_{DSF} | $I_{DR} = -14\text{ A}, V_{GS} = 0\text{ V}$ | — | — | 1.7 | V |
| Reverse recovery time | t_{rr} | $I_{DR} = -14\text{ A}, V_{GS} = 0\text{ V}$ | — | 110 | — | ns |
| Reverse recovery charge | Q_{rr} | $dI_{DR} / dt = 50\text{ A} / \mu\text{s}$ | — | 0.18 | — | μC |

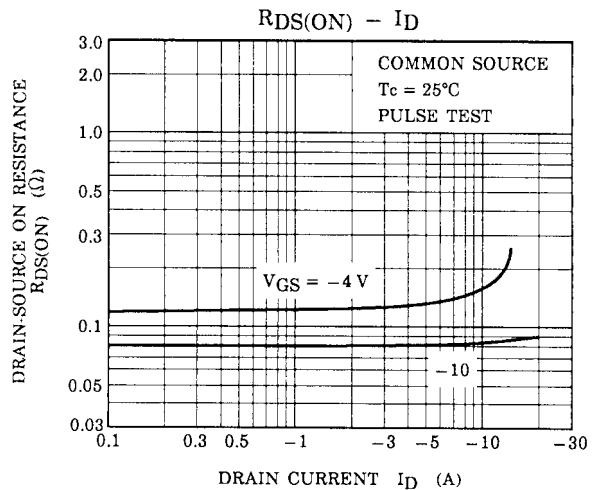
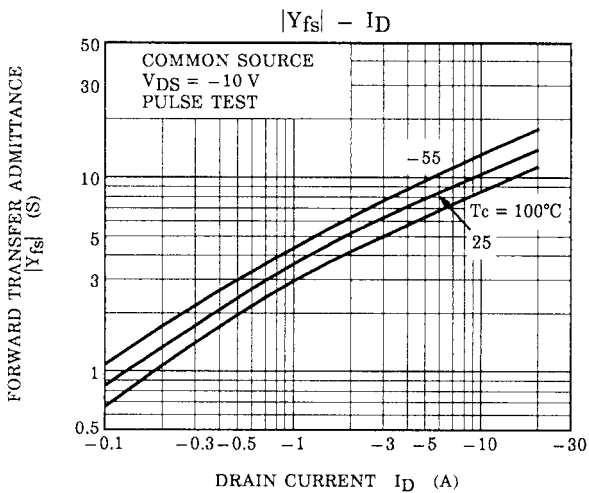
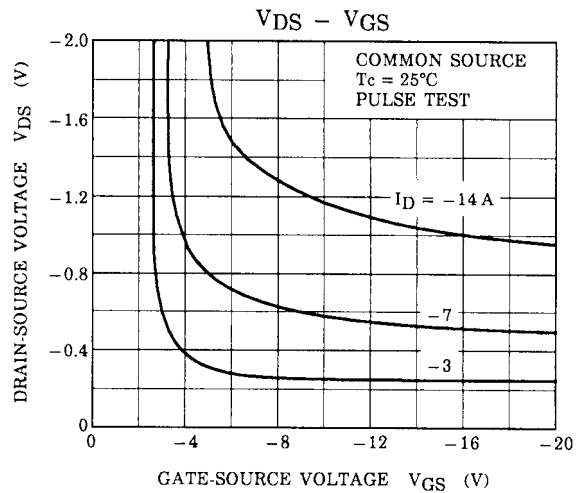
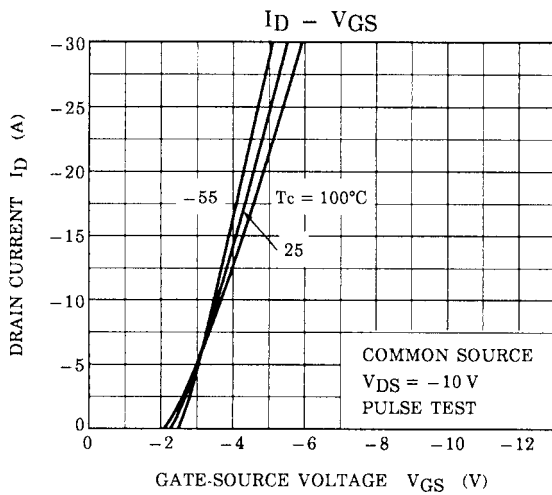
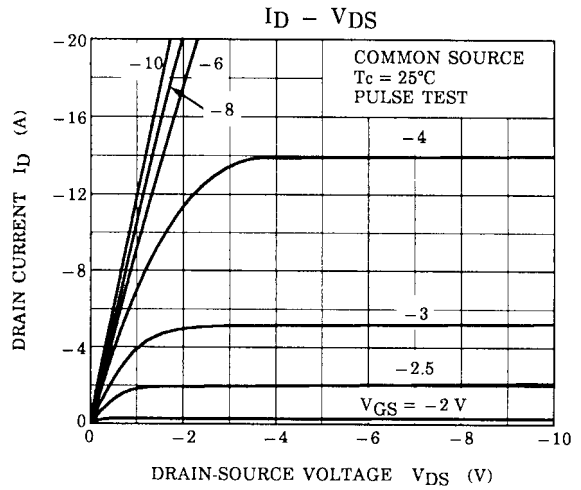
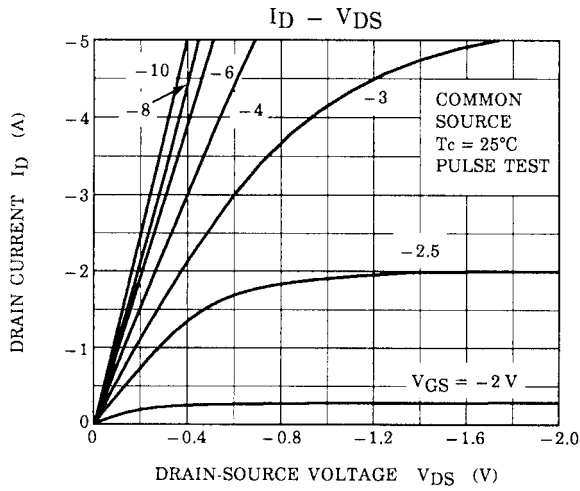
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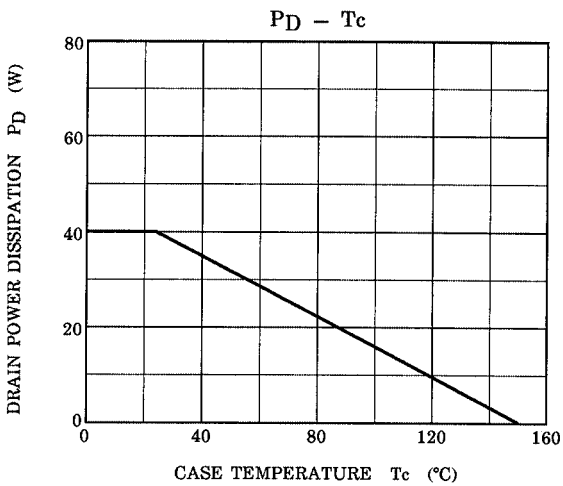
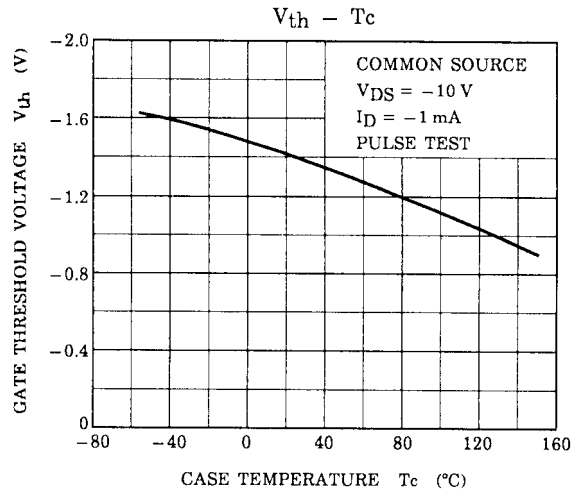
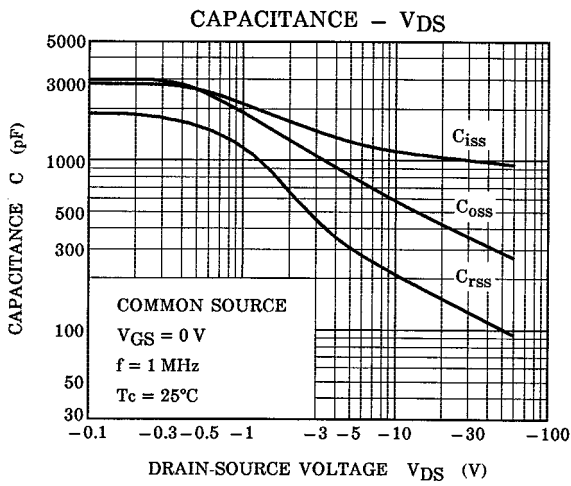
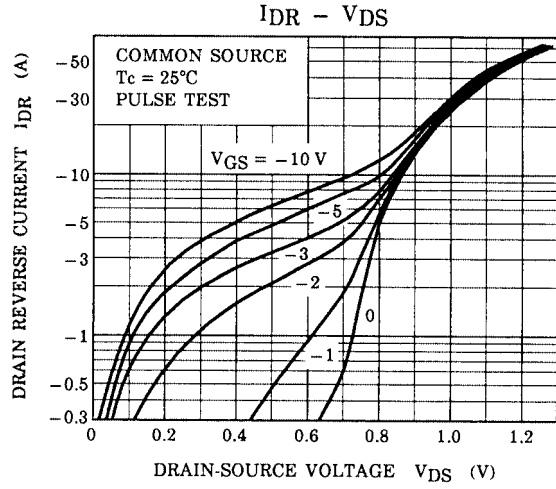
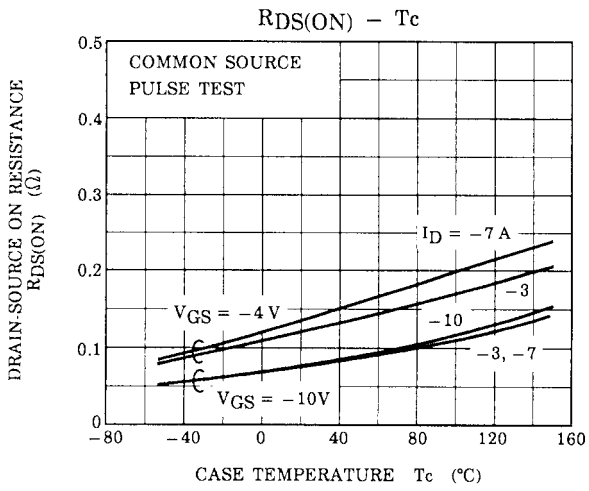


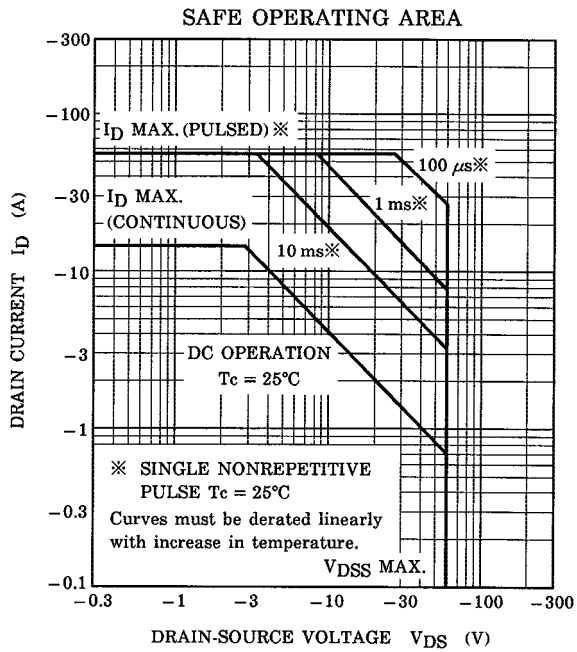
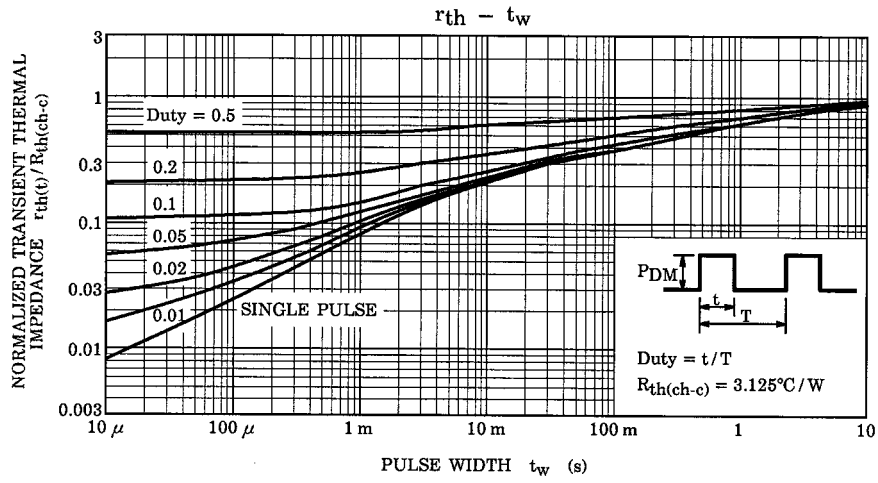
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